Application Specific Discretes
A.S.D. ${ }^{\text {T }}$

## TRANSILTM ARRAY FOR ESD PROTECTION

## APPLICATIONS

Where transient overvoltage protection in ESD sensitive equipment is required, such as :

- COMPUTER
- PRINTERS
- COMMUNICATION SYSTEMS

It is particulary recommended for RS232 I/O port protection where the line interface withstands only 2 kV ESD surges.

## FEATURES

- 6 BIDIRECTIONAL TRANSIL ${ }^{\text {TM }}$ FUNCTIONS
- VERY LOW CAPACITANCE : C= 20 pF @ VRM
- 150 W peak pulse power $(8 / 20 \mu \mathrm{~s})$


## DESCRIPTION

The ESDA25B1 is a monolithic voltage suppressor designed to protect components which are connected to data and transmission lines against EDS.

## BENEFITS

High ESD protection level : up to 25 kV
High integration
Suitable for high density boards

COMPLIES WITH THE FOLLOWING STANDARDS :
IEC 1000-4-2 : level 4

MIL STD 883C-Method 3015-6 : class 3
(human body model)


FUNCTIONAL DIAGRAM


ABSOLUTE MAXIMUM RATINGS ( $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$ )

| Symbol | Parameter | Value | Unit |
| :---: | :--- | :---: | :---: |
| $\mathrm{V}_{\mathrm{PP}}$ | Electrostatic discharge <br> MIL STD 883C - Method 3015-6 | 25 | kV |
| $\mathrm{P}_{\mathrm{PP}}$ | Peak pulse power (8/20 $\mathrm{\mu s})$ | 150 | W |
| $\mathrm{~T}_{\mathrm{Stg}}$ | Storage temperature range <br> Maximum junction temperature | $-55 \mathrm{to}+150$ <br> 125 | ${ }^{\circ} \mathrm{C}$ <br> ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{L}}$ | Maximum lead temperature for soldering during 10s | 260 | ${ }^{\circ} \mathrm{C}$ |

ELECTRICAL CHARACTERISTICS (Tamb $=25^{\circ} \mathrm{C}$ )

| Symbol | Parameter |
| :---: | :--- |
| $\mathrm{V}_{\mathrm{RM}}$ | Stand-off voltage |
| $\mathrm{V}_{\mathrm{BR}}$ | Breakdown voltage |
| $\mathrm{V}_{\mathrm{CL}}$ | Clamping voltage |
| $\mathrm{I}_{\mathrm{RM}}$ | Leakage current |
| $\mathrm{I}_{\mathrm{PP}}$ | Peak pulse current |
| $\alpha \mathrm{T}$ | Voltage temperature coefficient |
| C | Capacitance |
| Rd | Dynamic resistance |



| Types | min. note | @ max. | IR |  | Vm | Rd typ. note 2 | $\alpha T$ <br> max. <br> note 3 | C typ. OV bias |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | V | V | mA | $\mu \mathrm{A}$ | V | $\Omega$ | $10^{-4} /{ }^{\circ} \mathrm{C}$ | pF |
| ESDA25B1 | 25 | 30 | 1 | 2 | 24 | 1.5 | 9.7 | 15 |

note 1 : Between any I/O pin and Groung
note 2 : Square pulse, $1 \mathrm{pp}=25 \mathrm{~A}, \mathrm{tp}=2.5 \mu \mathrm{~s}$.
note 3: $\Delta \mathrm{V}_{\mathrm{BR}}=\alpha \mathrm{T}^{*}\left(\operatorname{Tamb}-25^{\circ} \mathrm{C}\right)^{*} \mathrm{~V}_{\mathrm{BR}}\left(25^{\circ} \mathrm{C}\right)$

## CALCULATION OF THE CLAMPING VOLTAGE

## USE OF THE DYNAMIC RESISTANCE

The ESDA family has been designed to clamp fast spikes like ESD. Generally the PCB designers need to calculate easily the clamping voltage $\mathrm{V}_{\mathrm{CL}}$. This is why we give the dynamic resistance in addition to the classical parameters. The voltage across the protection cell can be calculated with the following formula:

$$
V_{C L}=V_{B R}+R d l_{P P}
$$

Where lpp is the peak current through the ESDA cell.

## DYNAMIC RESISTANCE MEASUREMENT

The short duration of the ESD has led us to prefer a more adapted test wave, as below defined, to the classical $8 / 20 \mu \mathrm{~s}$ and $10 / 1000 \mu \mathrm{~s}$ surges.

$2.5 \mu \mathrm{~s}$ duration measurement wave.

As the value of the dynamic resistance remains stable for a surge duration lower than $20 \mu \mathrm{~s}$, the $2.5 \mathrm{\mu s}$ rectangular surge is well adapted. In addition both rise and fall times are optimized to avoid any parasitic phenomenon during the measurement of Rd.

Fig. 1 : Peak power dissipation versus initial junction temperature.


Fig. 3 : Clamping voltage versus peak pulse current (Tj initial = $25^{\circ} \mathrm{C}$ ).
Rectangular waveform $\mathrm{tp}=2.5 \mu \mathrm{~s}$.


Fig. 5 : Relative variation of leakage current versus junction temperature (typical values).


Fig. 2 : Peak pulse power versus exponential pulse duration ( Tj initial $=25^{\circ} \mathrm{C}$ ).


Fig. 4 : Capacitance versus reverse applied voltage (typical values).


ORDER CODE


MARKING : Logo, Date Code, E25B1

## PACKAGE MECHANICAL DATA

SO-8 Plastic


| REF. | DIMENSIONS |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | Millimeters |  |  | Inches |  |  |
|  | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A |  |  | 1.75 |  |  | 0.069 |
| a1 | 0.1 |  | 0.25 | 0.004 |  | 0.010 |
| a2 |  |  | 1.65 |  |  | 0.065 |
| a3 | 0.65 |  | 0.85 | 0.026 |  | 0.033 |
| b | 0.35 |  | 0.48 | 0.014 |  | 0.019 |
| b1 | 0.19 |  | 0.25 | 0.007 |  | 0.010 |
| C | 0.25 |  | 0.5 | 0.010 |  | 0.020 |
| c1 | $45^{\circ}$ (typ) |  |  |  |  |  |
| D | 4.8 |  | 5.0 | 0.189 |  | 0.197 |
| E | 5.8 |  | 6.2 | 0.228 |  | 0.244 |
| e |  | 1.27 |  |  | 0.050 |  |
| e3 |  | 3.81 |  |  | 0.150 |  |
| F | 3.8 |  | 4.0 | 0.15 |  | 0.157 |
| L | 0.4 |  | 1.27 | 0.016 |  | 0.050 |
| M |  |  | 0.6 |  |  | 0.024 |
| S |  |  | $8^{\circ}$ ( | max) |  |  |

Packaging : Preferred packaging is tape and reel.
Weight : 0.08g.

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